



Bipolar PNP Bare Die – BTP976

Part Description

The BTP976 is a silicon BJT transistor available in bare die form and well suited for use in general purpose switching and amplifier applications.

Key Parameters:

- VCBO = -50V
- VCEO = -40V
- VEBO = -5V
- hFE = 90-260 @ VCE = -2V, IC = -3A
- VCE(Sat) = -0.6V @ IC = -10A, IB = -330mA
- fT = 40 MHz @ VCE = -10V, IE = 0A
- COBO = 300pF @ VCB = -10V

Features

Low VCE(sat). Designed to provide performance equivalent to Panasonic 2SB936A

Die Size (Unawn)

2500 μ m X 2500 μ m, 98 Mils X 98 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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